DIGITAL OUTPUT PHOTO REFLECTOR

■ GENERAL DESCRIPTION

The NJL5801K is thin package digiral output type photo reflector which consist of New JRC original designed one chip photo recieving IC and high output LED.

■ FEATURES

- Normaly on type
- With schmitt triger circuit
- TTL Compatible
- Built-in visible light cut-off filter.

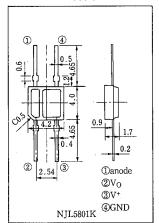
APPLICATIONS

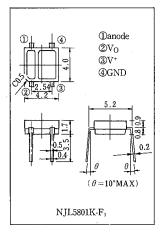
- Tape end sensor
- · Reel rotation sensor
- Paper detector, Paper end sensor
- Bar code reader
- Sensor of FDD, Robot, manufacturing installation, etc.

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

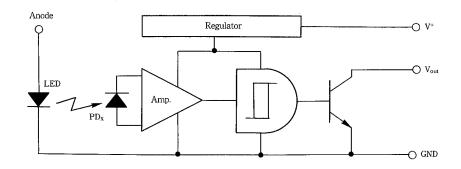
PARAMETER	SYMBOL	RATINGS	UNIT
Emitter			
Forward Current (Continuous)	IF	50	mA
Reverse Voltage (Continuous)	VR	6	v
Power Dissipation	PD	75	mW
Detector	1		
Supply Voltage	V+	16	v
High Level Output Voltage	VoH	16	v
Low Level Output Current	IoL	50	mA
Power Dissipation	Po	110	mW
Coupler			
Total Power Dissipation	Ptot	130	mW
Operating Temperature	Topr	$-20 \sim +85$	°C
Storage Temperature	Tstg	$-30 \sim +100$	°C
Soldering Temperature	Tsol	260	°C
		(5sec. 1.5mm from body)	

■ OUTLINE (typ.) Unit: mm





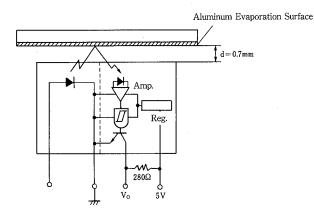
■ BLOCK DIAGRAM



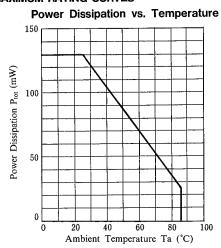
■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION		TYP.	MAX.	UNIT
Emitter						
Forward Voltage	V _F	$I_F = 10 \text{mA}$	l — .	1.1	1.3	V
Reverse Current	I_R	$V_R = 6V$		_	1.0	μA
Capacitance	Ct	$V_R = 0V$, $f = 1MHz$. —	25	_	pF
Detector						
Supply Voltage Range	V+		3,5		15	V
Low Level Output Voltage	V _{OL}	$I_{OL} = 16 \text{mA}, V^{+} = 5 \text{V}, I_{F} = 0 \text{mA}$	—	0.2	0.5	V
High Level Output Current	I _{OH}	$V_0 = V^+ = 15V$, $I_F = 10$ mA, $d = 0.7$ mm	<u> </u>	_	100	μ A
Low Level Supply Current	ICCL	$V^{+}=5V$, $I_F=0mA$	—	4.5	10	mA
High Level Supply Current	I _{CCH}	$V^{+}=5V$, $I_F=10mA$, $d=0.7mm$	_	3	10	mA
Coupled						
L→H Threshold Input Current	I _{FLH}	$V^{+}=5V$, $R_L = 280\Omega$, $d=0.7mm$		i —	10	mA
Hysteresis	I _{FHL} /I _{FLH}	$V^{+}=5V$, $R_L = 280\Omega$, $d=0.7mm$	—	0.8	—	
L→H Delay Time	tplH	$V^{+}=5V$, $R_{L}=280\Omega$, $I_{F}=10\text{mA}$, $d=0.7\text{mm}$	_	10	—	μs
H→L Delay Time	tPHL	$V^{+}=5V$, $R_L=280\Omega$, $I_F=10mA$, $d=0.7mm$	—	5	—	μs
Rise Time	t _r	$V^{+}=5V$, $R_{L}=280\Omega$, $I_{F}=10\text{mA}$, $d=0.7\text{mm}$		0.1		μs
Fall Time	tf	$V^{+}=5V$, $R_{L}=280\Omega$, $I_{F}=10mA$, $d=0.7mm$	—	0.1	—	μs
		· ·	1	1		

■ MEASURING SPECIFICATION FOR THRESHOLD INPUT CURRENT



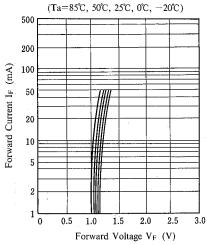
■ MAXIMUM RATING CURVES



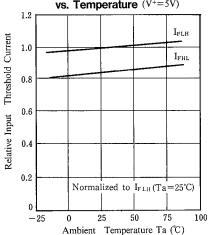
Forward Current vs. Temperature 60 50 40 40 10 0 0 20 40 60 80 100 Ambient Temperature Ta (°C)

■ TYPICAL CHARACTERISTICS

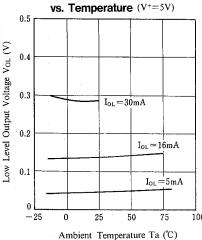
Forward Current vs. Forward Voltage



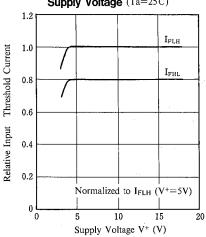
Input Threshold Current vs. Temperature (V+=5V)



Low Level Output Voltage

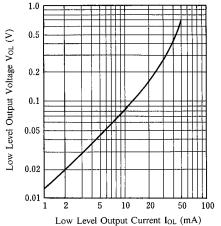


Input Threshold Current vs. Supply Voltage (Ta=25°C)

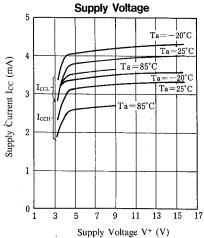


Low Level Output Voltage vs.

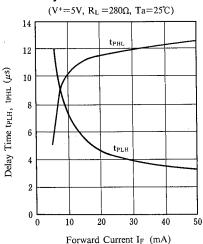
Low Level Output Current (V+=5V, Ta=25°C)



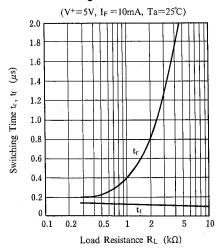
Supply Current vs.



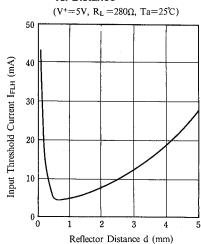
Delay Time vs. Forward Current



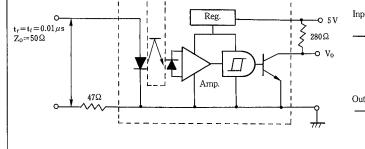
Switching Time vs. Resistance

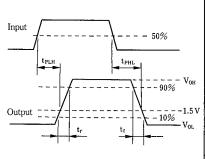


Input Threshold Current vs. Distance

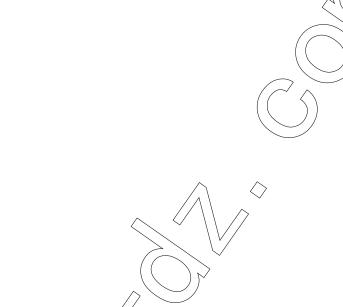


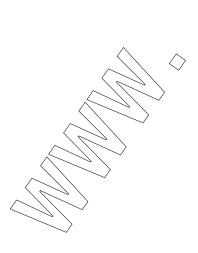
Measuring Circuit for Response Time





MEMO





[CAUTION]
The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.